

TOSHIBA Photocoupler Photo Relay

TLP594G

Modems

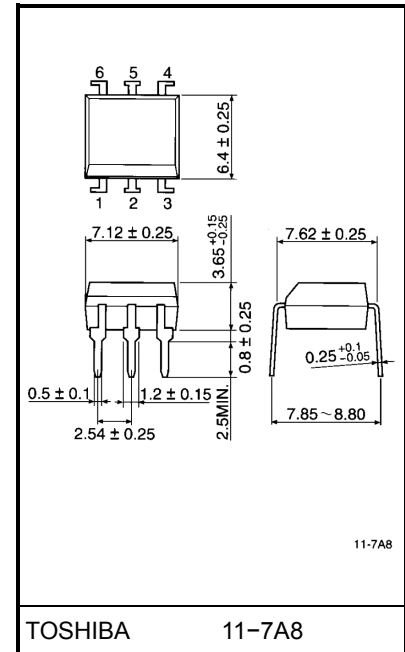
PBXes

Telecommunications

The TOSHIBA TLP594G consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a DIP (DIP6), which is suitable for equipment for high tech communications, including modems. The TLP594G complies with FCC part 68 rules with current limiting function.

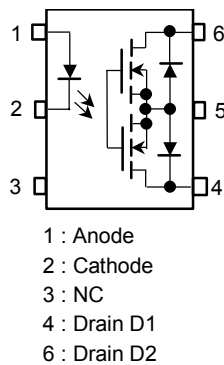
- Peak off-state voltage: 350V (min.)
- Trigger LED current: 3mA (max)
- On-state current: 120mA(max)
- Load current limiting: 150mA~300mA (t = 5ms)
- On-state resistance: 35Ω (max)
- Isolation voltage: 2500Vrms (min)
- UL recognized: UL1577, file no.E67349

Unit in mm

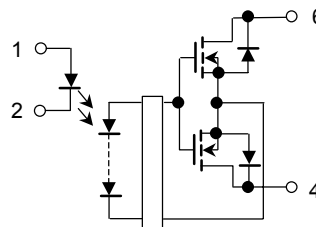


Weight: 0.4g

Pin Configurations (top view)



Schematic



Maximum Ratings (Ta = 25°C)

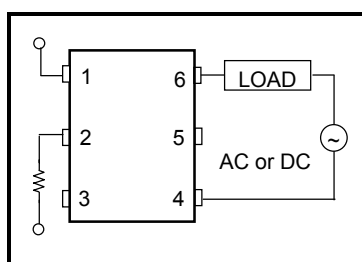
Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 25°C)	$\Delta I_F / ^\circ\text{C}$	-0.5	mA / °C
	Pulse forward current (100μs pulse, 100pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{OFF}	350	V
	On-state RMS current	I_{ON}	120	mA
	On-state current derating (Ta ≥ 25°C)	$\Delta I_{ON} / ^\circ\text{C}$	-1.2	mA / °C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	-55~125	°C
Operating temperature range		T_{opr}	-40~85	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)		BV_S	2500	Vrms

(Note 1): Device considered a two-terminal device: Pins1, 2 and 3 shorted together and pins4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	—	280	V
Forward current	I_F	5	7.5	25	mA
On-state current	I_{ON}	—	—	120	mA
Operating temperature	T_{opr}	-20	—	65	°C

Circuit Connections



Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
Detector	Off-state current	I_{OFF}	$V_{OFF} = 350\text{V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1\text{MHz}$	—	40	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	$I_{ON} = 120\text{mA}$	—	—	3	mA
On-state resistance	R_{ON}	$I_{ON} = 120\text{mA}, I_F = 5\text{mA}$	—	22	35	Ω
		$I_{ON} = 20\sim 120\text{mA}, I_F = 5\text{mA}$	—	26	40	Ω
Load current limiting	I_{LIM}	$I_F = 5\text{mA}, V_{DD} = 5\text{V}, t = 5\text{ms}$	150	—	300	mA

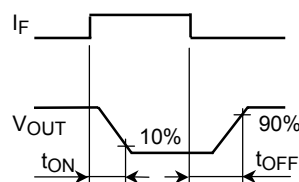
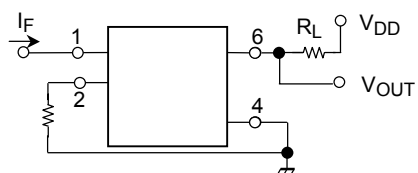
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	2500	—	—	V_{rms}
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	t_{ON}	$R_L = 200\Omega$ $V_{DD} = 20\text{V}, I_F = 5\text{mA}$ (Note2)	—	—	1	ms
Turn-off time	t_{OFF}		—	—	1	

(Note2): Switching time test circuit



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